

COMPLIANT

Standard Recovery Diodes, (Hockey PUK Version), 2100 A



B-PUK (DO-200AB)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	2100 A			
Package	B-PUK (DO-200AB)			
Circuit configuration	Single			

FEATURES

- Wide current range
- High voltage ratings up to 1000 V
- High surge current capabilities
- Diffused junction
- Hockey PUK version
- Case style B-PUK (DO-200AB)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- · High power drives
- · Auxiliary system supplies for traction applications

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
1		2100	A		
I _{F(AV)}	T _{hs}	55	°C		
1		3900	A		
IF(RMS)	T _{hs}	25	°C		
1	50 Hz	23 900	Δ		
I _{FSM}	60 Hz	25 000	A		
l ² t	50 Hz	2857	kA ² s		
	60 Hz	2608	KA-S		
V _{RRM}	Range	400 to 1000	V		
TJ		-40 to +180	°C		

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 180 °C mA		
	04	400	500			
VS-SD2000CL	08	800	900	60		
	10	1000	1100			



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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current		180° conduction, half sine wave		2100 (1040) A		
at heatsink temperature	I _{F(AV)}	Double side (s	single side) coole	ed	55 (85)	°C
Maximum RMS forward current	I _{F(RMS)}	25 °C heatsin	k temperature de	ouble side cooled	3900	
		t = 10 ms	No voltage		23 900	А
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied	Sinusoidal half wave, initial $T_J = T_J$ maximum	25 000	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		20 100	
		t = 8.3 ms	reapplied		21 000	
		t = 10 ms	No voltage reapplied		2857	kA ² s
Maximum 12t for fusing	l ² t	t = 8.3 ms			2608	
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM} reapplied		2020	
		t = 8.3 ms			1844	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10 ms, no voltage reapplied			28 570	kA²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $T_J = T_J$ maximum			0.74	V
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			0.86	V
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			0.13	mW
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$			0.12	11100
Maximum forward voltage drop	V_{FM}	$I_{pk} = 6000 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sinusoidal wave}$			1.55	V

THERMAL AND MECHANICAL SPECIFICATIONS PARAMETER SYMBOL TEST CONDITIONS VALUES			UNITS	
Maximum junction operating temperature range	T _J	1201 CONDITIONS	-40 to +180	°C
Maximum storage temperature range	T _{Stg}		-55 to +200	
Maximum thermal resistance, junction to heatsink	R _{thJ-hs}	DC operation single side cooled	0.073 K/W	
		DC operation double side cooled	0.031	r\/vv
Mounting force, ± 10 %			14 700 (1500)	N (kg)
Approximate weight			255	g
Case style		See dimensions - link at the end of datasheet B-PUK (DO-200)		-200AB)

△R _{thJ-hs} CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TECT CONDITIONS	LIMITO
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS
180°	0.009	0.009	0.006	0.006		
120°	0.011	0.011	0.011	0.011	$T_J = T_J$ maximum	
90°	0.014	0.014	0.015	0.015		K/W
60°	0.020	0.020	0.021	0.021		
30°	0.036	0.036	0.036	0.036		

Note

• The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC

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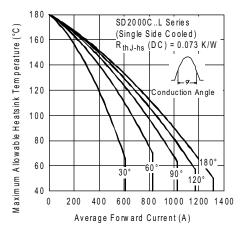


Fig. 1 - Current Ratings Characteristics

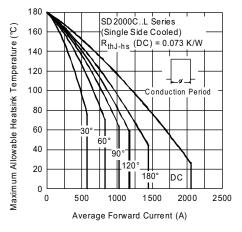


Fig. 2 - Current Ratings Characteristics

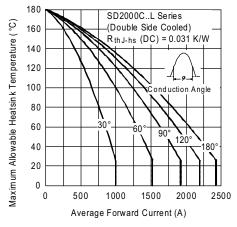


Fig. 3 - Current Ratings Characteristics

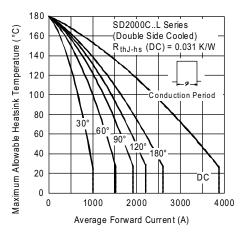


Fig. 4 - Current Ratings Characteristics

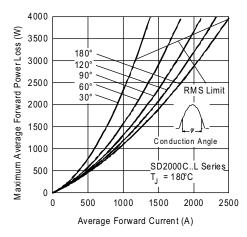


Fig. 5 - Forward Power Loss Characteristics

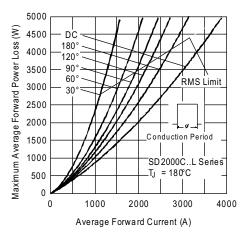


Fig. 6 - Forward Power Loss Characteristics

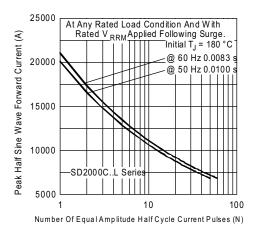


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

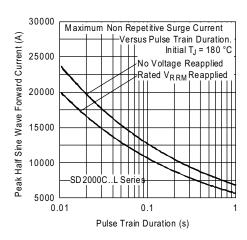


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

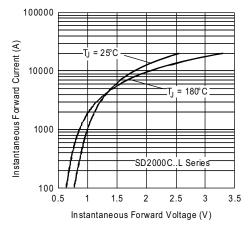


Fig. 9 - Forward Voltage Drop Characteristics

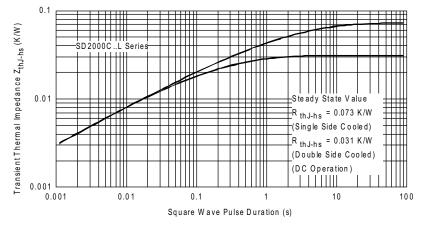
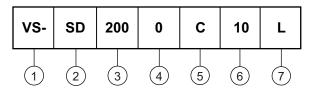


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Diode

Essential part number

- 0 = standard recovery

5 - C = ceramic PUK

6 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

7 - L = PUK case B-PUK (DO-200AB)

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95246			



B-PUK (DO-200AB)

DIMENSIONS in millimeters (inches)

3.5 (0.14) DIA. NOM. x
1.8 (0.07) deep MIN. both ends

VAW. YIO (08.7) (1.08) (0.03) both ends

2 places

C

Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)

53 (2.09) DIA. MAX.

Note: A = Anode

C = Cathode



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